#### UNIVERZITA KARLOVA V PRAZE

## matematicko-fyzikální fakulta

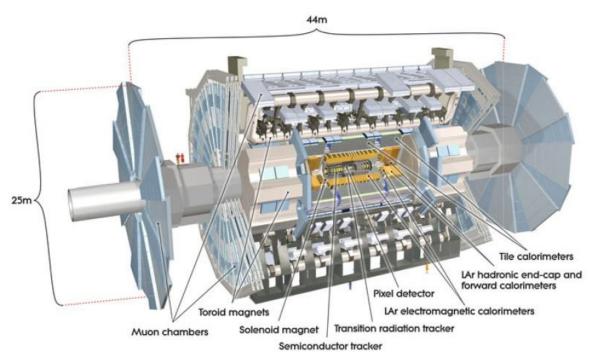


## **ATLAS ITk Upgrade Project**

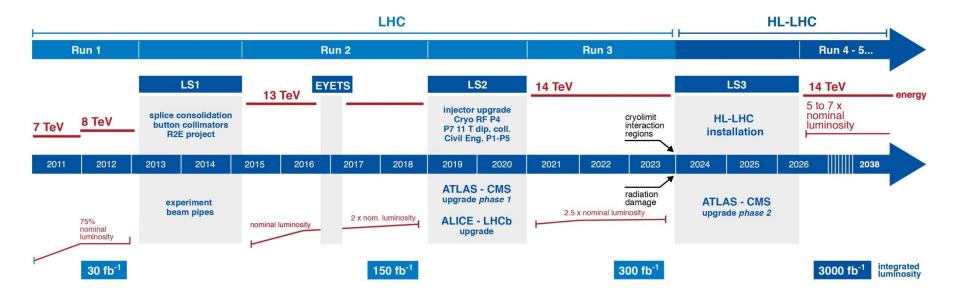
Zdeněk Doležal<sup>1</sup>, Peter Kodyš<sup>1</sup>, Jiří Kroll<sup>2</sup>, <u>Martin Sýkora<sup>1</sup></u>, Ondřej Theiner<sup>1</sup>, Ondřej Kovanda<sup>1</sup>, Marek Martaus<sup>1</sup>, Lýdia Janitorová<sup>1</sup>, Martin Kaplan<sup>1</sup>

<sup>1</sup>Faculty of Mathematics and Physics, Charles University in Prague <sup>2</sup>Institute of Physics, The Czech Academy of Sciences

- general-purpose experiment at the LHC, interaction point
- cylindrical symmetry, several detection subsystems
  - inner detector (ID) track, vertex, momentum and charge reconstruction
  - calorimeter (LAr, TileCal) energy reconstruction
  - muon spectrometer (CSC, MDT, RPC, TGC) muon detection
- magnet system
  - central solenoid (2 T)
  - outer toroid (4 T)



#### **HL-LHC** and Upgrades

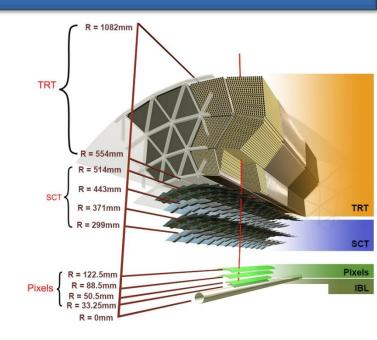


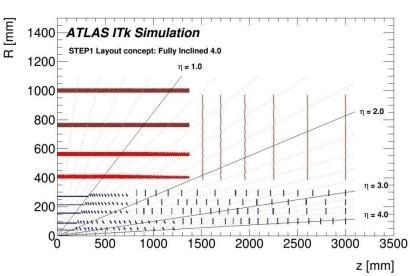
- 2018: last year of Run 2, physics in May, goal 60 fb<sup>-1</sup> (50 fb<sup>-1</sup> in 2017)
- LS2: injector upgrade Linac 2 -> Linac 4, ATLAS calorimeter trigger systems
- LS3: LIU plans new SPL and PS2, upgraded SPS

ATLAS ID replacement for Inner Tracker (ITk)

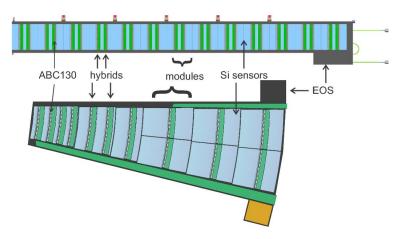
### ITk Upgrade

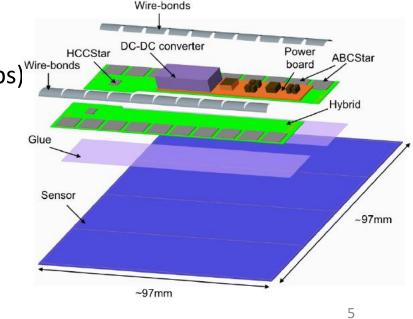
- current ID coverage IηI = 2.5
  - 4 barrel layers and 6 endcap discs of pixels
  - 4 barrel layers and 18 endcap discs of strips
  - TRT layer with straw tubes
- future ITk all-silicon tracker, coverage IηI = 4
  - 5 barrel layers of pixels in inclined layout
  - 32-38 endcap discs in each of 4 pixel layers
  - 4 barrel layers and 12 endcap discs of strips
- motivation radiation resistance
  - the most resistant layer IBL up to 850 fb<sup>-1</sup>





- 28 barrel modules create stave and 18 endcap modules create petal
- 6 rings (R0-R5) in petal with different design
- module design:
  - ABC readout chips and HCC control chip UV-glued on kapton PCBs (hybrid)
  - hybrid glued directly on silicon sensor
  - wire bonding (chips on hybrid, strips on chips)
  - power board, end of structure

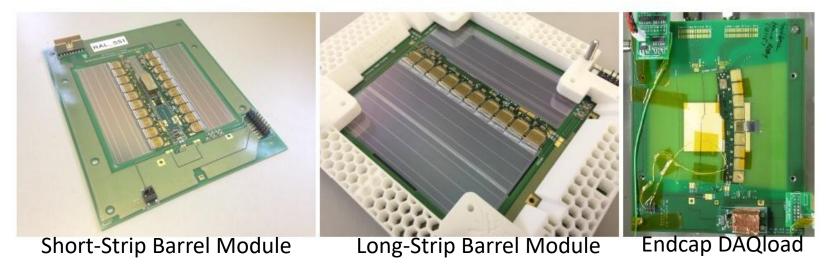


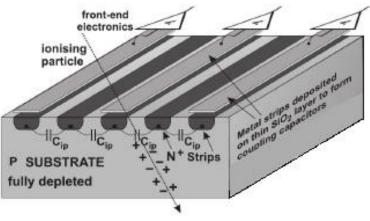


n<sup>+</sup> strips in p silicon bulk in case of ITk

- larger signal after irradiation than p-in-n (SCT)

- depletion zone width  $W = \sqrt{\frac{2\epsilon}{e} \left(\frac{N_A + N_D}{N_A N_D}\right) V_{bi}} \cong \sqrt{\frac{2\epsilon V_{bi}}{e N_D}}$
- sensor width 320 μm, depletion voltage 350 V
- strip pitch 75.5 μm (barrel) and 70-80 μm (endcap discs)
- testing prototypes

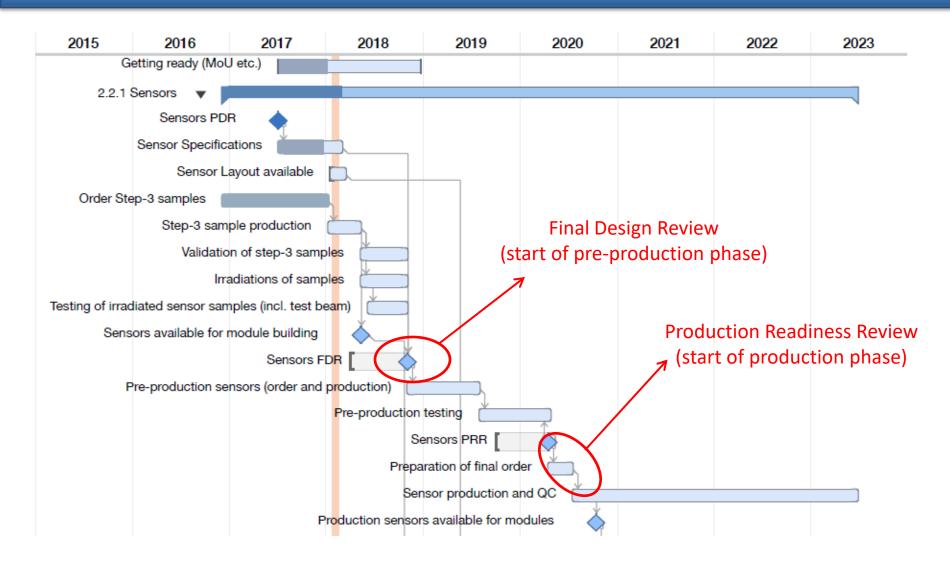




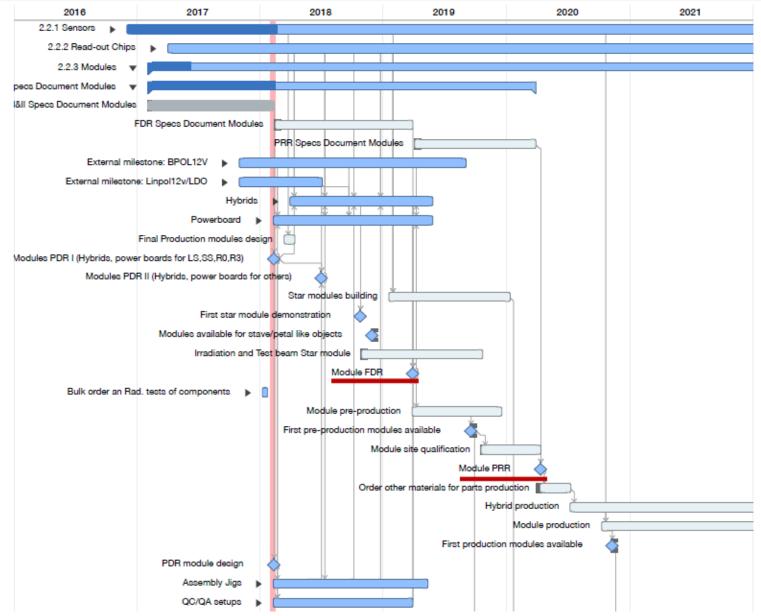
#### **Overview of Strip (ITk) Community Activities**

- Sensors/Hybrids/Modules assembly, testing
- ASICs development of chips
- On-detector control/readout electronics EoS development, monitoring systems
- Local support electrical and mechanical concept of staves/petals
- Global support carrying of local substructures such as staves/petals
- Database
- Powering/cables/off-detector electronics
- Common mechanics/electronics
- Cooling

#### Working Schedule and Milestones - Sensors



#### Working Schedule and Milestones - Hybrids/Modules

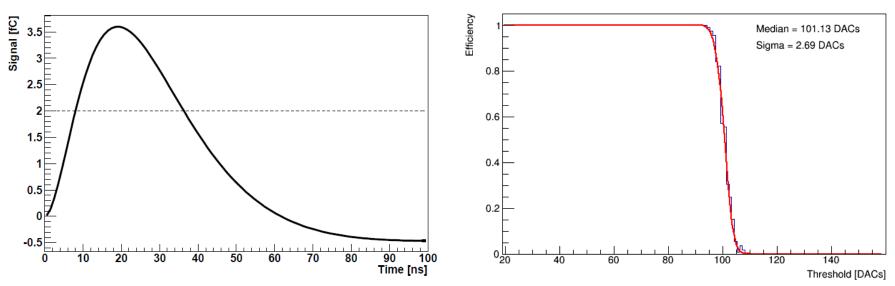


#### Testing of Strip Modules - Threshold Scan

- testing = charge injection into sensor/chip channels + (triggered) readout
- basic ITSDAQ scan, amplitude reconstruction using binary readout
- integral form of convolution of noise and signal distribution
- critical parameters:

$$f(x) = \epsilon_{max} Erfc \left[ x \left( 1 + 0.6 \frac{e^{-\xi x} - e^{\xi x}}{e^{-\xi x} + e^{\xi x}} \right) \right]$$

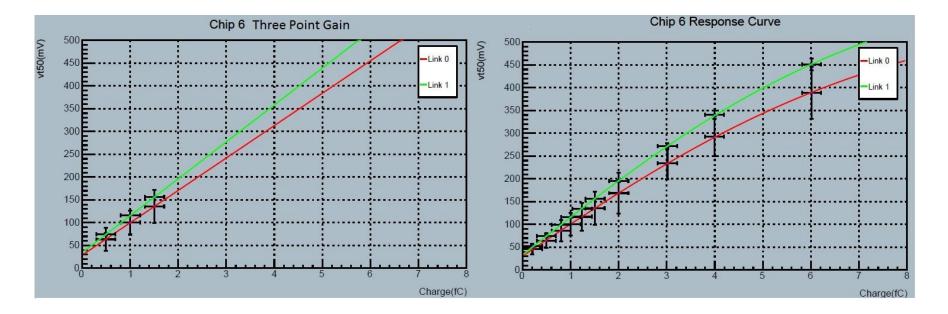
- collected charge, noise, hit efficiency, gain, S/N



Threshold scan at 3.01 fC

#### **Testing of Strip Modules - Calibration**

- internal ITSDAQ units DACs, conversion to fC required
- DACs-to-mV conversion using ABC130 chip simulation
- mV-to-fC conversion using injected charge through calibration circuit
- Three Point Gain (linear, gain + offset), Response Curve (non-linear, 3 parameters)

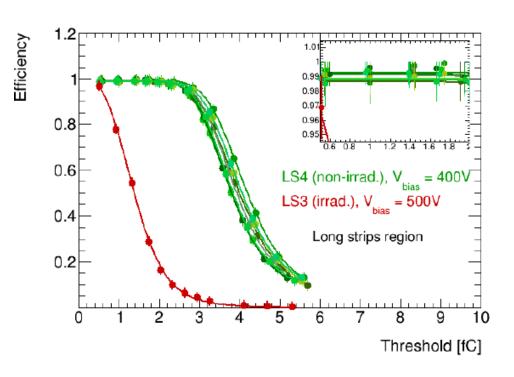


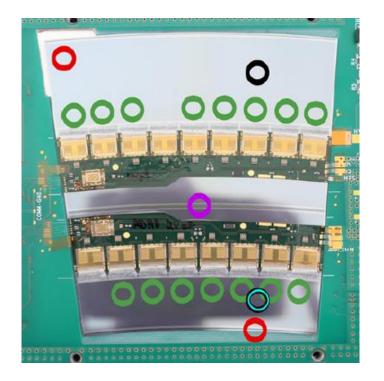
- accelarated particle beam, expensive, less available, including tracking
  - CERN (120 GeV pions), DESY (4 4.8 GeV electrons)
- DAQloads, SS, LS, R0 modules so far (J. Kroll Test beam coordinator)



#### Testing of Strip Modules - Test Beam

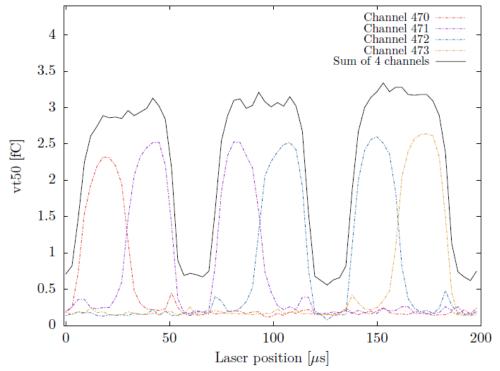
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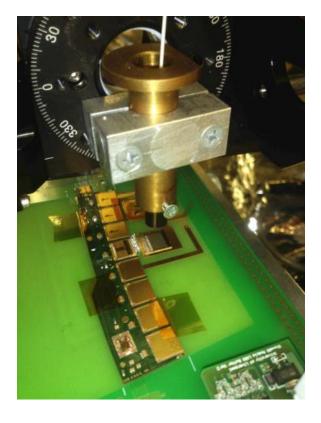




#### **Testing of Strip Modules - Laser Tests**

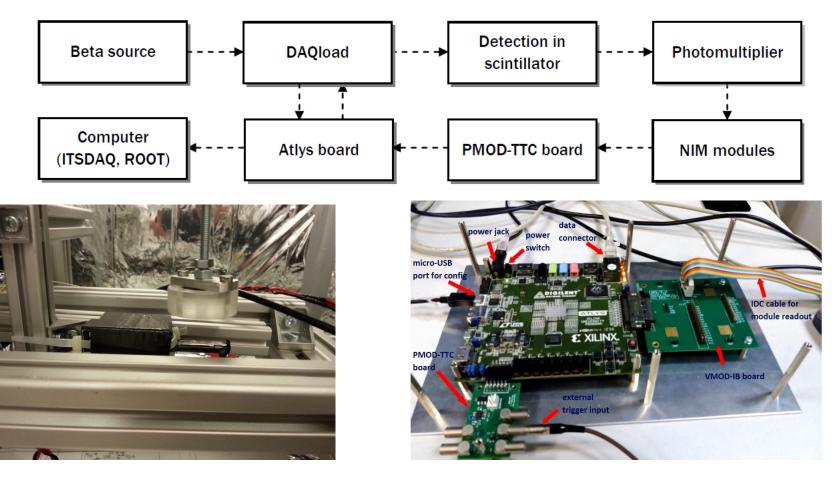
- available, cheap, good spatial resolution, adjustable intensity
- in operation at IPNP (O. Theiner, M. Martaus)
- 3-axis motorised translation stages, red/infra-red laser, pulse generator
- strip-by-strip scan + interstrip charge collection





#### **Testing of Strip Modules - Beta Source Tests**

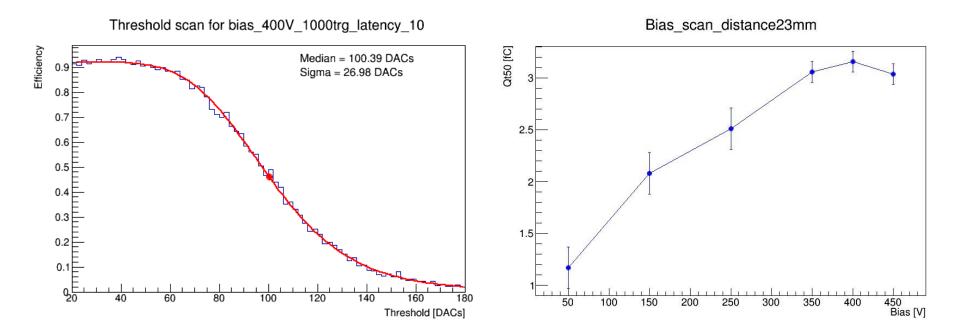
- beta source <sup>90</sup>Sr, e<sup>-</sup> collimated, mini sensor 1 x 1 cm<sup>2</sup> (M. Sýkora, O. Kovanda)
- scintillator as an external trigger, Atlys board for readout, software ITSDAQ, ROOT



#### **Testing of Strip Modules - Beta Source Tests**

- bias scan, angular scan, temperature scan, FE parameters scan, latency scan
- collected charge 3.1 fC , noise (ENC) 550 e<sup>-</sup> , S/N 35
- sensor fully depleted above 350 V

 $ENC\left[fC\right] = \frac{\sigma\left[mV\right]}{gain\left[mV/fC\right]}$ 



#### **Testing of Strip Modules - Beta Source Tests**

• collected charge 2.1 fC	Module Type	Fluence 10 <sup>14</sup> n <sub>eq</sub> cm <sup>-2</sup>	Charge ke <sup>-</sup> 500 V	Charge <i>ke</i> - 700 V	Noise <i>e</i> <sup>-</sup>	S/N 500 V	S/N 700 V
<ul> <li>collected charge 3.1 fC</li> </ul>	SS	8.1	13.7	16.1	630	21.8	25.6
	LS	4.1	17.3	19.5	750	23.1	26.0
<ul> <li>noise (ENC) 550 e<sup>-</sup></li> </ul>	RO	12.3	11.5	14.0	650	17.7	21.5
	R1	10.1	12.5	15.0	640	19.6	23.4
• S/N <mark>35</mark>	R2	8.7	13.3	15.7	660	20.3	23.9
	R3	8.0	13.8	16.2	640	21.4	25.1
	R4	6.8	14.6	17.0	800	18.4	21.3
=> non-irrad. R0 mini sensor	R5	6.0	15.3	17.6	840	18.3	21.1

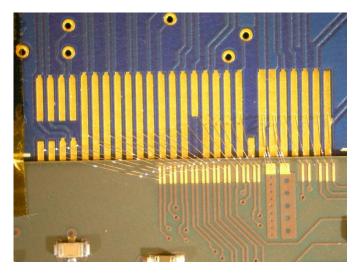
Channel number

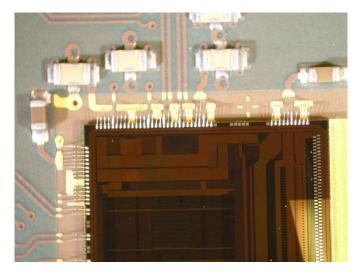
Channel hits for bias\_400V\_1500trg\_distance\_3mm VThr (DAQ counts) 79.29 60.28 Entries Mean x Mean y 22.66 32.53 RMS x RMS 

- hit map for 128 channels
  - cut-off rules for analysis:
    - 1 cluster/event
    - cluster size < 6

- share of Czechia for production approx. 650 EC R2/R4 modules (9 10 %)
- including partial assembly:
- completed electrical hybrids should be glued on sensor and wire-bonded
  - => cooperation with the czech private company Argotech based in Trutnov

=> now being tested, plan to built fully functional R0 module together



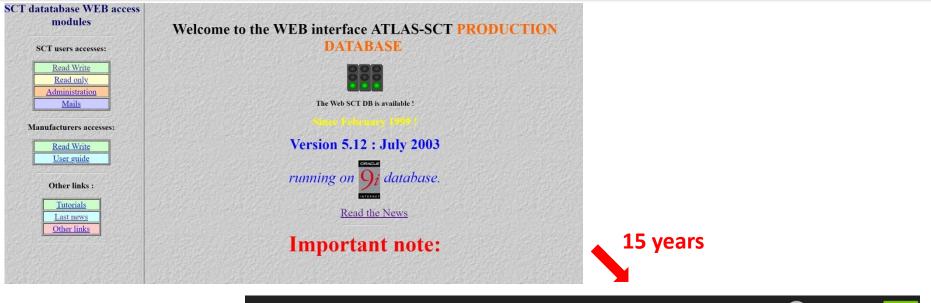


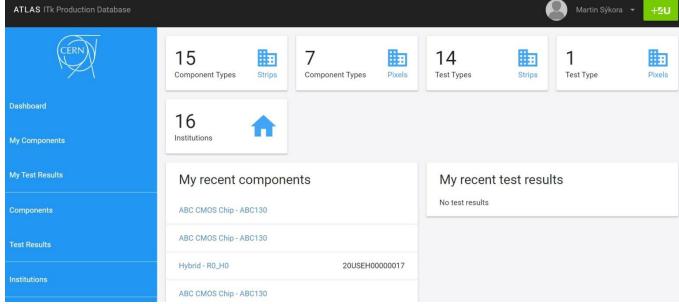
- thermal cycling, metrology (L. Janitorová), continuous QC testing, database entry

- to record details of used components, their assembly, shipments, test results
- being designed by the Unicorn College, just 1 DB for the whole ITk
- should stay accessable during ITk operation for better understanding of defects
- SCT DB ~ 350 000 registered items ; ITk DB ~ 10<sup>6</sup> 10<sup>7</sup> numbered items

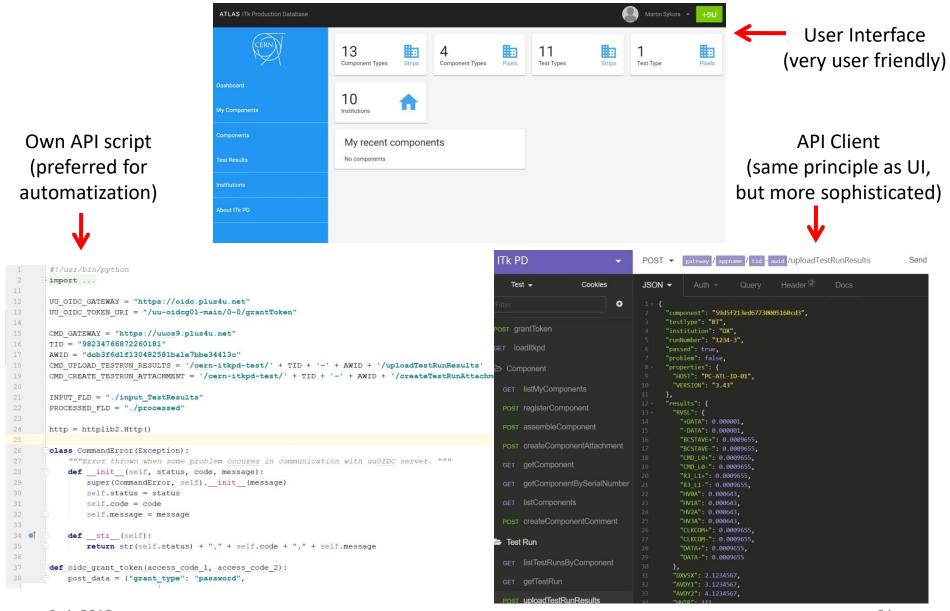
- current status:
  - basic testing version of PD is already running
  - UC gradually adds new types of components/tests according to our specification
  - still more and more ITk collaboration people are getting in touch with PD

#### **Production Database - User Interface**

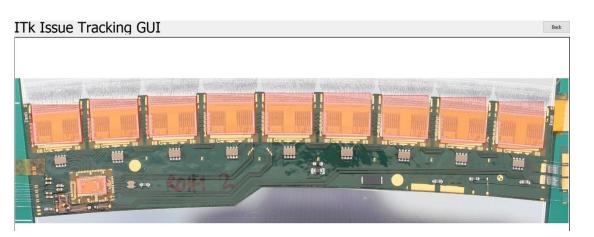


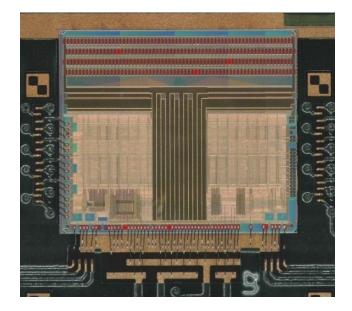


#### **Production Database - Communication Methods**

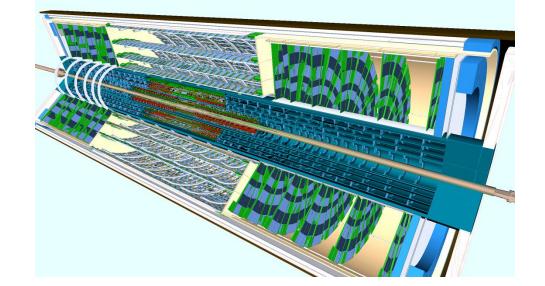


- to develop API scripts for various purposes of PD focusing on ITSDAQ integration
   => respond to changes in new DB releases (commands definition slightly differs)
- registration/update/deleting/assembly of components, comments, attachments
- starting to add definition of test types and their parameters
  - => script for Visual Inspection data upload to the DB for purposes of tracking GUI



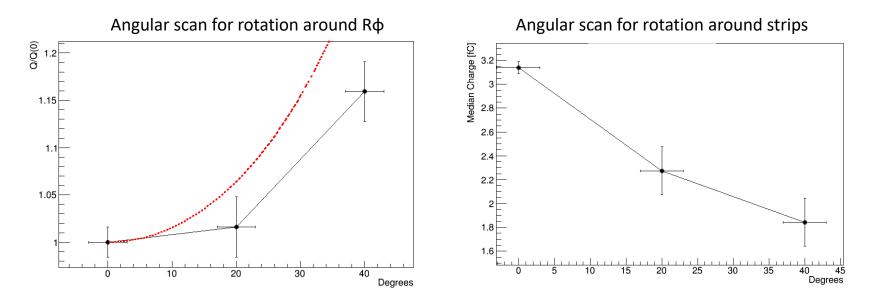


- all-silicon ITk will replace current ID in 2025, 8 types/designs of modules
- production is comming (Q2 2020), ITk final settlement (2024 -2026)
- Prague group involved in sensor/hybrid/mod. testing, module assembly, database
- at IPNP successful tests of DAQloads (laser, beta source) + QC testing
- near future RO assembly and its testing, CERN/DESY test beams
- functional working team of supervisors (3) and students (6), newcomers welcome

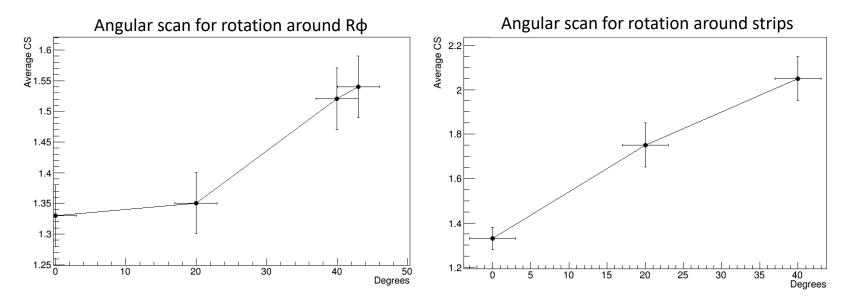


# BACKUPS

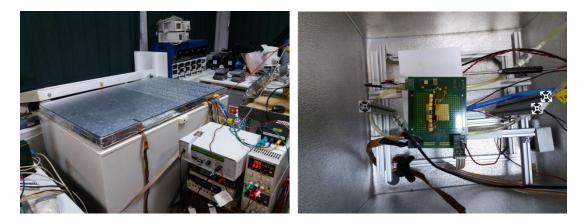
- source rotation around axis perpendicular to strips in the sensor plane
  - decrease of Vt50 and increase of cluster size
  - comparison with geometric relation  $1/cos(\alpha)$  (red doted line)
- source rotation around axis parallel to strips
  - increase of Vt50 and cluster size



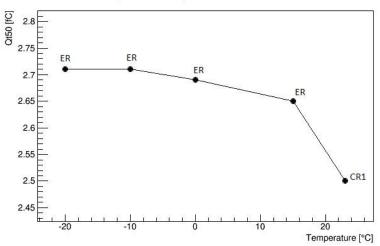
- source rotation around axis perpendicular to strips in the sensor plane
  - decrease of Vt50 and increase of cluster size
- source rotation around axis parallel to strips
  - increase of Vt50 and cluster size
- cluster size = number of neighboring strips with hit



measurement at 250 V, setup moved to the freezer in Electronic Room (ER)



• up to -20°C, small discrepancy between ER and CR1 in collected charge

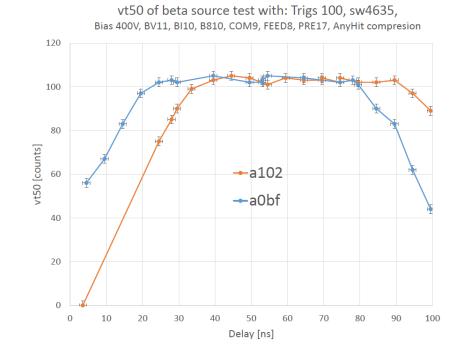


Temperature dependence at bias 250  $\rm V$ 

• possible explanation: shorter cabling in CR1

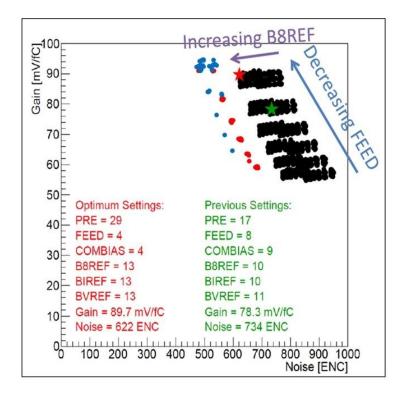
=> larger delay between external trigger signal and readout signal

- integer ITSDAQ variable latency (step 25 ns), finer latency scan with delay unit
- Atlys firmware version problem, preset latency value 10 changed to 11

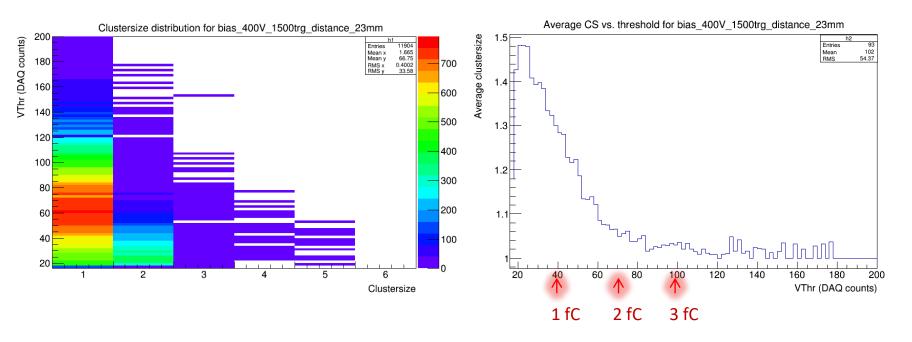


- 6 internal parameters of front-end electronics of ABC130 chip
- to adjust control currents and voltages, possible change of pulse shape
- search for best setting (high gain, low noise)

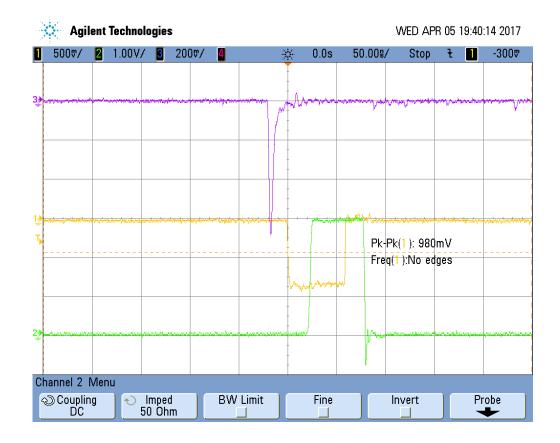
- new recommended setting
- collected charge 3.1 fC -> 2.8 fC
- noise 550 e<sup>-</sup> -> 500 e<sup>-</sup>



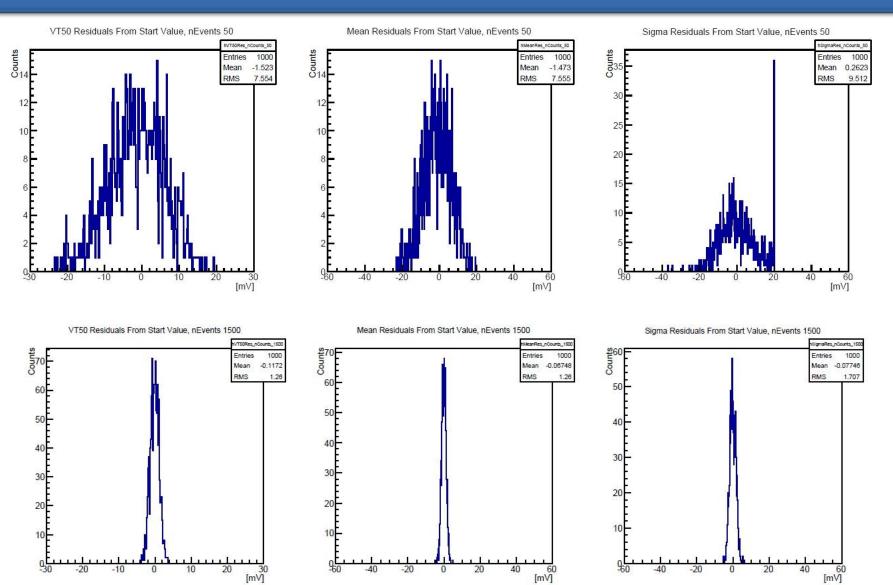
- cluster reconstruction from event lists
- sum of clusters for every cluster size gives S-curve
- average CS at 1 fC: 1.33 (fully depleted, perpendicular scan)

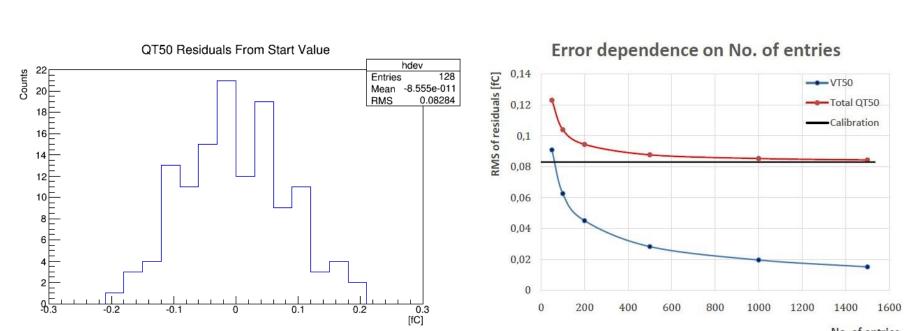


negative analogue signal from scintillator does not meet Atlys requirements
 => signal modulation using NIM crate (Discriminator, Level Adapter modules)



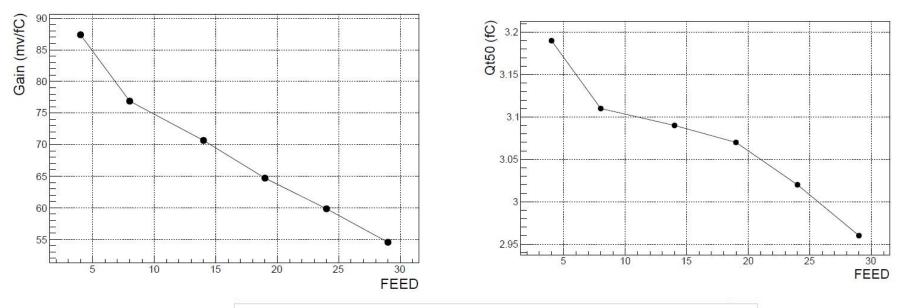
#### **Error Estimation**

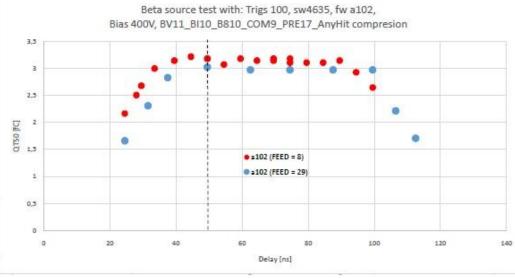




No. of entries

#### **FE Parameters**





9.4.2018

#### Test Beam

Module Type	Fluence 10 <sup>14</sup> n <sub>eq</sub> cm <sup>-2</sup>	Charge ke <sup>-</sup> 500 V	Charge ke <sup>-</sup> 700 V	Noise <i>e</i> <sup>-</sup>	S/N 500 V	S/N 700 V
SS	8.1	13.7	16.1	630	21.8	25.6
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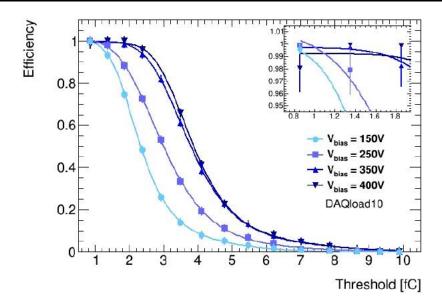


Figure 8.12: Efficiency versus threshold for one sensor on DAQload10, at four different bias voltages.

#### **Production of Petals**

